Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L17	594	((below or under or underlying) near5 trench).ti,ab,clm. and (charge)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:22
L18	134	((below or under or underlying) near5 trench).ti,ab,clm. and (charge).ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:28
L19	39	((below or under or underlying) near5 trench).ti,ab,clm. and (charge).ti,ab,clm. and mosfet	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:29
L20	3	(column near5 (below or under or underlying) near5 trench).ti,ab, clm. and (charge).ti,ab,clm. and mosfet	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:30
L21	19	(column near5 (below or under or underlying) near5 trench)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:30
L22	1	(column near5 (below or under or underlying) near5 trench) and (trench near mosfet)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:30
L23	8	((conductive or conducting or column) near5 (below or under or underlying) near5 trench) and (trench near mosfet)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:32
L24	42	((conductive or conducting or column or drain) near5 (below or under or underlying) near5 trench) and (trench near mosfet)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:35
L25	26	((conductive or conducting or column or drain) near5 (below or under or underlying) near5 trench) and (trench near mosfet) and charge	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:35

L26	1	((conductive or conducting or drain) near5 column near5 (below or under or underlying) near5 trench) and (trench near mosfet) and charge	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:36
L27	2	((conductive or conducting or drain) near5 column near5 (below or under or underlying) near5 trench)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:36
L28	24	((conductive or conducting or drain) near5 (region or portion or column) near5 (below or under or underlying) near5 trench) and (trench near mosfet) and charge	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:36
L29	10	((conductive or conducting or drain) near5 (region or portion or column) near5 (below or under or underlying) near5 trench).clm. and (trench near mosfet) and charge	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:41
L30	24	((conductive or conducting or drain) near5 (region or portion or column) near5 (below or under or underlying) near5 trench) and (trench near mosfet) and charge	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:41
L31	28	((conductive or conducting or drain) near5 (region or portion or column) near5 (below or under or underlying) near5 trench) and (trench near2 mosfet) and charge	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:43
L32	52	((region or portion or column) near2 (below or under or underlying) near5 trench) and (trench near2 mosfet) and charge	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:43
L33	30	((region or portion or column) near2 (below or under or underlying) near2 trench) and (trench near2 mosfet) and charge	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:45
L34	95	((region or portion or column) near2 (below or under or underlying) near2 trench) and (mosfet) and charge	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:45
L35	5	((region or portion or column) near2 (below or under or underlying) near2 trench) and (mosfet) and (charge near (balance or balancing or balanced))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:48

L36	4	((region or portion or column) near2 (below or under or underlying) near2 trench) and (mosfet).ti,ab,clm. and (charge near (balance or balancing or balanced))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:47
L37	5	((region or portion or column or section) near2 (below or under or underlying) near2 trench) and (mosfet) and (charge near (balance or balancing or balanced))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:48
L38	5	((region or portion or column or section) near3 (below or under or underlying) near2 trench) and (mosfet) and (charge near (balance or balancing or balanced))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:48
L39	6	((region or portion or column or section) near3 (below or under or underlying) near3 trench) and (mosfet) and (charge near (balance or balancing or balanced))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:48
L40	6	((region or portion or column or section) near3 (below or under or underlying) near3 trench) and (mosfet) and (charge near (balance or balancing or balanced)) and (trench near5 drain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:49
L41	4	((region or portion or column or section) near3 drain near3 (below or under or underlying) near3 trench) and (mosfet) and (charge near (balance or balancing or balanced)) and (trench near5 drain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:51
L42	4	((region or portion or column or section) near5 drain near5 (below or under or underlying) near5 trench) and (mosfet) and (charge near (balance or balancing or balanced)) and (trench near5 drain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:51
L43	4	((region or portion or column or section) near5 drain near5 (below or under or underlying) near5 trench) and (mosfet) and (charge near (balance or balancing or balanced))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:51

L44	8	((region or portion or column or section) near5 drain near5 (below or under or underlying) near5 trench) same charge	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:52
L45	248	((region or portion or column or section) near5 drain near5 (below or under or underlying) near5 trench)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:52
L46	74	((region or portion or column or section) near5 drain near5 (below or under or underlying) near5 trench).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:52
L47	40	((region or portion or column or section) near5 drain near5 (below or under or underlying) near5 trench).clm. and mosfet	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 12:52